

## AT45DB641E-MHN-T

Data Sheet

64Mbit, 1.7 V to 3.6 V Range SPI Serial Flash Memory

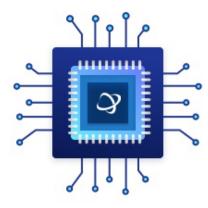
Manufacturers Renesas Technology Corp

Package/Case

Product Type Memory

**RoHS** 

Lifecycle



Images are for reference only

Please submit RFQ for AT45DB641E-MHN-T or <a href="mailto:sales@ovaga.com"><u>Email to us: sales@ovaga.com</u></a> We will contact you in 12 hours.



## **General Description**

## **Features**

Includes controllable Dual R/W SRAM buffers for maximum flexibility

Standard block architecture with added 256-byte page erase for energy efficient Data Logging

Byte-write provides Serial EEPROM functionality in a Serial NOR Flash device

Extended Vcc operation allows the system memory to operate over the entire voltage range

Ultra-deep power down

Comprehensive security and unique ID features protect the device from outside tampering

## **Related Products**



Renesas Technology Corp SOIC-8

AT45DB641E-SHN2B-T



AT45DB021E-SHN-B
Renesas Technology Corp
SOIC-8



AT25DF321A-MH-T
Renesas Technology Corp
UDFN-8



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AT45DB161E-SHD-B



AT45DB081E-SSHN-B Renesas Technology Corp SOIC-8



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